

United States Patent and Trademark Office



UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/615,332	07/08/2003	Sven Lindfors	ASMMC.043AUS	8737
	7590 11/02/200 RTENS:OLSON & BE	EXAM	EXAMINER	
2040 MAIN ST	REET	STOUFFER	STOUFFER, KELLY M	
FOURTEENTH FLOOR IRVINE, CA 92614			ART UNIT	PAPER NUMBER
			1792	
			NOTIFICATION DATE	DELIVERY MODE
			11/02/2007	ELECTRONIC

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

Notice of the Office communication was sent electronically on above-indicated "Notification Date" to the following e-mail address(es):

jcartee@kmob.com eOAPilot@kmob.com

	Application No.	Applicant(s)			
	10/615,332	LINDFORS, SVEN			
Office Action Summary	Examiner	Art Unit			
	Kelly Stouffer	1792			
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the c	orrespondence address			
A SHORTENED STATUTORY PERIOD FOR REPLY WHICHEVER IS LONGER, FROM THE MAILING DA - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. If NO period for reply is specified above, the maximum statutory period value is Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be timused and will expire SIX (6) MONTHS from a cause the application to become ABANDONE	N. nely filed the mailing date of this communication. D (35 U.S.C. § 133).			
Status					
1) Responsive to communication(s) filed on 24 Se	eptember 2007.				
2a) ☐ This action is FINAL . 2b) ☑ This	This action is FINAL . 2b)⊠ This action is non-final.				
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is					
closed in accordance with the practice under E	Ex parte Quayle, 1935 C.D. 11, 48	53 O.G. 213.			
Disposition of Claims					
4) ☐ Claim(s) 12-17,19-26 and 30-34 is/are pending 4a) Of the above claim(s) is/are withdray 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 12-17,19-26 and 30-34 is/are rejected 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restriction and/o	wn from consideration.	·			
Application Papers	·				
9) ☐ The specification is objected to by the Examine	ır				
10) ☐ The drawing(s) filed on is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.					
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).					
Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the Ex	•				
Priority under 35 U.S.C. § 119					
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority application from the International Bureau * See the attached detailed Office action for a list	s have been received. s have been received in Applicat rity documents have been receive u (PCT Rule 17.2(a)).	ion No ed in this National Stage			
Attachment(s) 1) Notice of References Cited (PTO-892)	4) 🔲 Interview Summary				
Notice of Draftsperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO/SB/08) Paper No(s)/Mail Date	Paper No(s)/Mail D 5) Notice of Informal F 6) Other:				

DETAILED ACTION

Continued Examination Under 37 CFR 1.114

1. A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on 24 September 2007 has been entered.

Response to Arguments

2. Applicant's arguments filed 24 September 2007 have been fully considered but they are not persuasive. The applicant argues that Murakami does not disclose valves and passages that have a purpose related to draining unvaporized liquid back to the reservoir. However, the recitation of draining and returning the liquid back to the reservoir is a recitation of the intended use of the valves and passages and must result in a structural difference between the claimed invention and the prior art in order to patentably distinguish the claimed invention from the prior art. If the prior art structure is capable of performing the intended use, then it meets the claim. As was stated in the previous office actions, there are no structural differences between that of Murakami and the invention as claimed; therefore they are capable of performing the invention. Modisette further evidences this, giving motivation for using the valves and passages of

Murakami in this manner, to recover and reuse valuable material (see below and previous office actions). In response to applicant's arguments against the references individually, one cannot show nonobviousness by attacking references individually where the rejections are based on combinations of references. See *In re Keller*, 642 F.2d 413, 208 USPQ 871 (CCPA 1981); In re Merck & Co., 800 F.2d 1091, 231 USPQ 375 (Fed. Cir. 1986). Further, the applicant argues that the references fail to show certain features of applicant's invention, it is noted that the features upon which applicant relies (i.e., advantages detailed on page 7 of the instant arguments) are not recited in the rejected claim(s). Although the claims are interpreted in light of the specification, limitations from the specification are not read into the claims. See In re Van Geuns, 988 F.2d 1181, 26 USPQ2d 1057 (Fed. Cir. 1993). Also the fact that applicant has recognized other advantages (again see page 7 of the instant argument) which would flow naturally from following the suggestion of the prior art cannot be the basis for patentability when the differences would otherwise be obvious. See Ex parte Obiaya, 227 USPQ 58, 60 (Bd. Pat. App. & Inter. 1985).

In addition, one of "a person of ordinary skill has good reason to pursue the known options with his or her technical grasp. If this leads to the anticipated success, it is likely the product not of innovation but of ordinary skill and common sense." One of ordinary skill in the art would certainly find it within their technical grasp and known options to use the apparatus of Murakami as claimed especially in view of Modisette. Also, this claim limitation would have been obvious because the invention resulted from application of the prior knowledge in a predictable manner, i.e. Modisette as applied to

Application/Control Number: 10/615,332

Art Unit: 1792

the Murakami reference. See KSR International Co. v. Teleflex Inc., 550 U.S.--, 82 USPQ2d 1385 (2007).

New grounds of rejection appear below necessitated by amendment.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

The factual inquiries set forth in *Graham* v. *John Deere Co.*, 383 U.S. 1, 148 USPQ 459 (1966), that are applied for establishing a background for determining obviousness under 35 U.S.C. 103(a) are summarized as follows:

- 1. Determining the scope and contents of the prior art.
- 2. Ascertaining the differences between the prior art and the claims at issue.
- 3. Resolving the level of ordinary skill in the pertinent art.
- 4. Considering objective evidence present in the application indicating obviousness or nonobviousness.
- 3. Claims 12-14, 19-23, 26, and 30 are rejected under 35 U.S.C. 103(a) as being unpatentable over US Patent number 6126994 to Murakami et al. in view of US Patent number 3981156 to Modisette et al. and in further view of US Patent number 7063981 to Bondestram et al.

In claim 12, the applicant claims a method for providing a vapor phase reactant from a solid or liquid source that requires the source being fed from storage chamber

into a vaporization chamber with higher temperature. The source is vaporized in the vaporization chamber, used in a vapor deposition process and the unused source is drained from the vaporization chamber without opening the vaporization chamber. Murakami et al. shows a method where a liquid material L is stored in reservoir 4 and travels into the evaporator 8 in Figure 1. The evaporator and evaporates the liquid material L that travels into the deposition chamber as described in column 2 lines 53-64. The evaporator is heated due to its proximity to heating means 68 and 70 in Figure 1 and in column 5 lines 57-67. Murakami et al. shows a discharge passage 52 that collects unvaporized liquid from the evaporator 8 and is connected to reservoir 4 in Figure 1. Though Murakami et al. does not explicitly disclose the unvaporized liquid flowing from discharge passage 52 into reservoir 4, one of ordinary skill in the art would recognize that the only utility of connecting a discharge passage from the evaporator into the reservoir, especially given valve VB and line 20, would be to drain unvaporized liquid back into the reservoir that would eventually travel back to the vaporizer. Further, Modisette et al. teaches that one would want to recover vapors in chemical processes and return them to a storage container to prevent the loss of valuable material (column 1 lines 25-30). Though the vaporization of Modisette et al. occurs from a pressurized container naturally, it would be obvious to one of ordinary skill in the art that this recycling of materials also applies to the storage container of Murakami et al. as it is pressurized but adds energy to vaporize the material with liquid left over that will not be used and needs to be recycled to prevent the loss of valuable material. Murakami et al.

provides gas passageway 52 that would be used in a process such as the one taught by Modisette et al.

It would have been obvious to one of ordinary skill in the art at the time of the invention to modify Murakami et al. to include recycling the unvaporized liquid material back into the storage container and vaporizer as taught by Modisette et al. in order to prevent the loss of valuable material.

Murakami et al. and Modisette et al. are described above and include a vapor deposition process for the method previously described. Murakami et al. does not describe this method as an ALD method or supplying pulses of the vaporized precursor alternatingly with another vaporized precursor. Bondestram et al. teaches an ALD system with alternating pulses of two vaporized reactant sources in column 6 lines 17-43 to better control the growth mechanism of the film on the substrate in column 1 lines 21-48. It would have been obvious to one of ordinary skill in the art at the time of the invention to modify Murakami et al. and Modisette et al. to include the method as an ALD method or supplying pulses of the vaporized precursor alternatingly with another vaporized precursor as taught by Bondestram et al. in order to better control the growth mechanism of the film on the substrate. Bondestram et al. additionally describes an ALD method with an inert gas purging in between pulses and a valve for controlling the flow of said gas out of a vaporization chamber in column 6 lines 17-43 and shown by valve 30 in Figure 1.

Application/Control Number: 10/615,332

Art Unit: 1792

With regard to claim 13, the liquid materials used by Murakami et al. are described as precursors in column 1 lines 40-51.

Regarding claim 14, an unvaporized liquid is maintained in the vaporizer that maintains the vaporization process in column 5 lines 10-21 and shown in Figure 3.

Regarding claim 19, Murakami et al. shows a pump 62 in Figure 1 is used with discharge passage 52 when it becomes more difficult to remove the unvaporized liquid (column 5 lines 26-40).

Regarding claim 20, Murakami et al. describes a cold trap 60 in Figure 1 for removing liquid from the exhaust out of discharge passage 52 in column 5 lines 26-40. This can be considered a dedicated drain container for the unvaporized liquid, at least as broadly recited by the applicant in claim 20.

With regard to claim 21, Murakami et al. discloses an apparatus including reservoir that will stably supply the low-pressure liquid material for film deposition (this may be broadly interpreted to include supplying the liquid material stably with respect to temperature) in column 2 lines 28-33. The liquid material L is also said to be under normal temperature and normal pressure in column 3 lines 62-66.

With regard to claim 22, the vaporization chamber keeps the precursor below its boiling pressure, as it does not vaporize the precursor by heat, but by an evaporation gas. (column 4 lines 60-67, column 5 lines 1-9).

With regard to claims 23 and 26, Murakami et al. describes heating means 68 that may be described as a hot zone with the reaction and vaporizer chambers included (at least as broadly described in claim 26) as shown in Figure 1. Heating means 68

Application/Control Number: 10/615,332 Page 8

Art Unit: 1792

includes heaters for the vapor feed passage from the vaporizer chamber to the reaction chamber (at a temperature sufficient) to prevent the evaporated gas from re-liquefying in column 5 lines 57-63.

4. Claims 15 and 16 are rejected under 35 U.S.C. 103(a) as being unpatentable over Murakami et al., Modisette et al. and Bondestram et al. in view of US Patent number 5376409 to Kaloyeros et al. Murakami et al., Modisette et al. and Bondestram et al. include a liquid precursor to be vaporized in a vaporizer. Murakami et al., Modisette et al. and Bondestram et al. do not include a solid dissolved in a solvent as a precursor to be vaporized. Kaloyeros et al. teaches the delivery of solid precursors in liquid solution to be vaporized in order to allow low vaporization temperatures of a solid an ease of transportation of the mixture of a precursor and solvent to a chemical vapor deposition reactor in column 3 lines 27-34.

It would have been obvious to one of ordinary skill in the art at the time of the invention to modify Murakami et al., Modisette et al. and Bondestram et al. to include vaporizing a solid dissolved in a solvent as taught by Kaloyeros et al. in order to allow low vaporization temperatures of a solid an ease of transportation of the mixture of a precursor and solvent to a chemical vapor deposition reactor.

5. Claims 17, 31 and 32 are rejected under 35 U.S.C. 103(a) as being unpatentable over Murakami et al., Modisette et al. and Bondestram et al. in view of Kaloyeros et al. as applied above, and further in view of US Patent number 6178925 to Sturm et al.

Murakami et al., Modisette et al., Bondestram et al. and Kaloyeros et al. are described above and include the provisions of claim 17 except for the solid remains of the unvaporized mixture being drained by adding solvent to the vaporization chamber.

Sturm et al. teaches a solvent flush approach that flushes the residual solid from a left over in the vaporizer with a solvent in order to dissolve the residual solvent residue and remove it from the vaporizer. (Column 2 lines 28-37)

It would have been obvious to one of ordinary skill in the art at the time of the invention to modify Murakami et al., Modisette et al., Bondestram et al. and Kaloyeros et al. to include a solvent flush approach as taught by Sturm et al. in order to dissolve the residual solvent residue and remove it from the vaporizer.

Regarding claims 31 and 32, Sturm et al. discloses the draining in the form of a solvent flush that is performed regularly between each coating cycle in column 2 lines 37-42 or at the end of the day, at the end of the week, or when the wafer is changed in the system in column 6 lines 30-38.

6. Claims 24 and 25 are rejected under 35 U.S.C. 103(a) as being unpatentable over Murakami et al., Modisette et al. and Bondestram et al. in view of US Patent number 5882416 to Van Buskirk et al. Murakami et al., Modisette et al. and Bondestram et al. are described above and include all the provisions of claims 24 and 25 except a vaporization chamber maintained in a first hot zone, a reaction chamber maintained in a second hot zone where the two hot zones share some insulating elements. Van Buskirk et al. teaches heating systems for both the vaporization chamber and reaction chamber

that may be one heating system or hot zone sharing insulating elements or separate heating systems or hot zones to prevent condensation of the vapor on any other surfaces besides the substrate in column 10 lines 25-62.

It would have been obvious to one of ordinary skill in the art at the time of the invention to modify Murakami et al., Modisette et al. and Bondestram et al. to include a vaporization chamber maintained in a first hot zone, a reaction chamber maintained in a second hot zone where the two hot zones share some insulating elements as taught by Van Buskirk et al. in order to prevent condensation of the vapor on any other surfaces besides the substrate.

7. Claims 33 and 34 rejected under 35 U.S.C. 103(a) as being unpatentable over Murakami et al., Modisette et al. and Bondestram et al. in view of US Patent number 6007330 to Gauthier. Murakami et al., Modisette et al. and Bondestram et al. are described above and include all the recitations of claims 33 and 34 except for a method to sense the level of unvaporized liquid in the vaporization chamber and automatically refill the unvaporized liquid. Gauthier teaches a method to sense the level of the unvaporized liquid and automatically refill the storage container and thereby refill the vaporization chamber to allow the system to run essentially continuously in column 5 lines 2-14.

It would have been obvious to one of ordinary skill in the art at the time of the invention to modify Murakami et al., Modisette et al. and Bondestram et al. to include a method to sense the level of the unvaporized liquid and automatically refill the storage

Application/Control Number: 10/615,332 Page 11

Art Unit: 1792

container and thereby refill the vaporization chamber as taught by Gauthier in order to allow the system to run essentially continuously.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Kelly Stouffer whose telephone number is (571) 272-2668. The examiner can normally be reached on Monday - Thursday 7:00-5:30.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Timothy Meeks can be reached on (571) 272-1423. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

Kelly Stouffer Examiner Art Unit 1792

M kms

FRED S. PARKER
PRIMARY EXAMINER